Middle Power LED Series
3030

LM302D

CRI 70

Features & Benefits

- 0.9 W class middle power LED
- Mold resin for high reliability
- Standard form factor for design flexibility (3.0 × 3.0 mm)

SAMSUNG

Table of Contents

1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_a	-40 ~ +85	℃	-
Storage Temperature	T_{stg}	-40 ~ +100	℃	-
LED Junction Temperature	T_j	125	℃	-
Forward Current	I_F	200	mA	-
Pulse Forward Current	I_{FP}	300	mA	Duty 1/10, pulse width 10ms
Assembly Process Temperature	-	260 <10	℃ s	-
ESD (HBM)	-	5	kV	-

b) Electro-optical Characteristics (I_F = 150 mA, Ts = 25℃)

Item	Unit	Rank	Bin	Min.	Typ.	Max.
Forward Voltage (VF)	V	GA	AZ	6.0	-	6.1
			A1	6.1	-	6.2
			A2	6.2		6.3
			A3	6.3	-	6.4
Reverse Voltage (@ 5 mA)	V			0.7	-	1.2
Color Rendering Index (R_a)	-	3		70	-	-
R9				-40		
Thermal Resistance (junction to solder point)	℃/W			-	12	-
Beam Angle	°			-	120	-

Note:

Samsung maintains measurement tolerance of: forward voltage = ±0.1 V, luminous flux = ±5 %, CRI = ±3, , R9 = ±6.5

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	M	W	H	3	3	2	7	F	S	3	G	A	V	Y	S	F

Digit	PKG Information	Code	Specification		
1 2 3	Samsung Package Middle Power	SPM	Middle power		
4 5	Color	WH	White		
6	Product Version	3	Zener-in		
7 8 9	Form Factor	327	3.0 x 3.0 x 0.65 mm; 2 pads		
10	Sorting Current	F	150 mA		
11	Chromaticity Coordinates	S	MacAdam		
12	CRI	3	Min. 70		
13 14	Forward Voltage (V)	GA	6.0~6.4	Bin Code:	AZ 6.0~6.1 A1 6.1~6.2 A2 6.2~6.3 A3 6.3~6.4
15 16	CCT (K)	V☆	3000	Bin Code	VN, VP, VQ, VR, VS, VT, VU
		U☆	3500		UN, UP, UQ, UR, US, UT, UU
		T☆	4000		TN, TP, TQ, TR, TS, TT, TU
		R☆	5000		RN, RP, RQ, RR, RS, RT, RU
			☆ : "0" (Whole Bin) or "Y"(Y Kitting) or "3"(MacAdam 3 step)		
17 18	Luminous Flux (lm)	SF		Bin Code	SF

a) Luminous Flux Bins(I_F = 150 mA, T_s= 25℃)

Nominal CCT (K)	CRI Min.	Product Code	Flux Bin	Flux Range (Φ_v, lm)
3000	70	SPMWH3327FS3GAV☆SF	SF	150 ~ 160
3500	70	SPMWH3327FS3GAU☆SF	SF	152 ~ 162
4000	70	SPMWH3327FS3GAT☆SF	SF	158 ~ 168
5000	70	SPMWH3327FS3GAR☆SF	SF	158 ~ 168

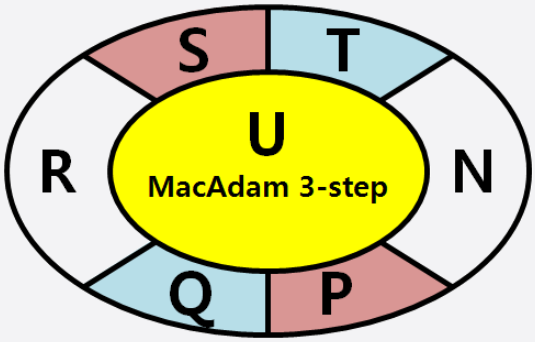
Note: “☆” can be “0” (Whole bin), “3” (MacAdam 3-step), "Y" (Kitting).

b) Kitting Rule

1) Y Kitting Bin Concept

1. Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (Color).
2. A Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

[Kitting example]



[Binning Information]

Item	Bin #1	Bin #2
VF	AZ	AZ
	A1	A1
	A2	A2
	A3	A3
CIE	U	U
	N	R
	P	S
	Q	T
IV	SF	SF

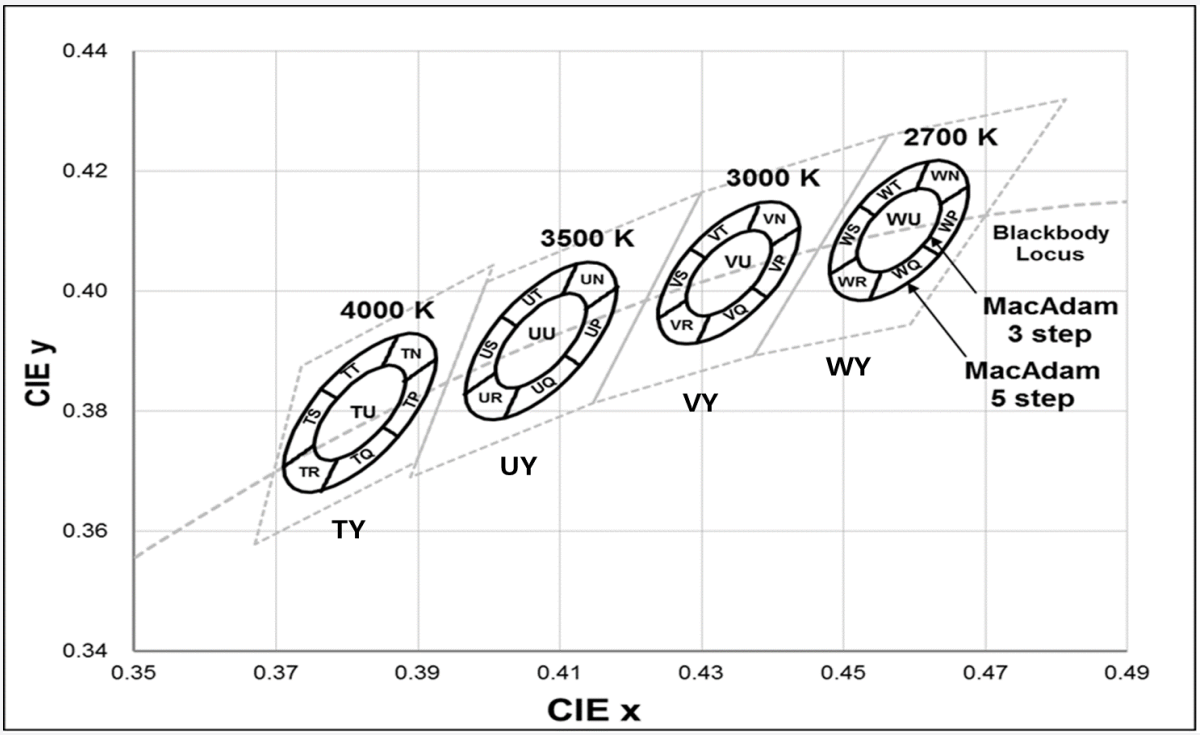
c) Color Bins (I_F = 150 mA, Ts= 25℃)

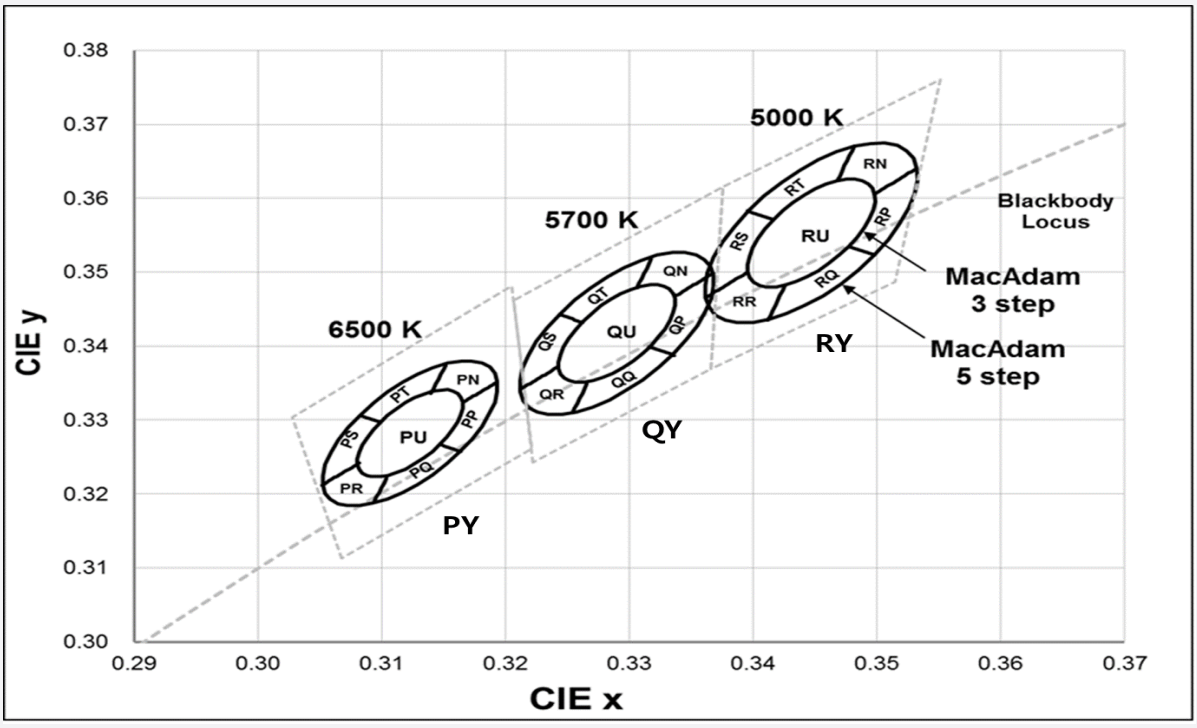
min. CRI (Ra)	Nominal CCT (K)	Product Code		Color Rank	Chromaticity Bins
70	3000	SPMWH3327FS3GAV0SF	V0	Whole bin (MacAdam 5 only)	V0
		SPMWH3327FS3GAV3SF	V3	MacAdam 3-step ellipse bin	VU
		SPMWH3327FS3GAVYSF	VY	Y Kitting	VN, VP, VQ, VR, VS, VT, VU
	3500	SPMWH3327FS3GAU0SF	U0	Whole bin (MacAdam 5 only)	U0
		SPMWH3327FS3GAU3SF	U3	MacAdam 3-step ellipse bin	UU
		SPMWH3327FS3GAUYSF	UY	Y Kitting	UN, UP, UQ, UR, US, UT, UU
	4000	SPMWH3327FS3GAT0SF	T0	Whole bin (MacAdam 5 only)	T0
		SPMWH3327FS3GAT3SF	T3	MacAdam 3-step ellipse bin	TU
		SPMWH3327FS3GATYSF	TY	Y Kitting	TN, TP, TQ, TR, TS, TT, TU
	5000	SPMWH3327FS3GAR0SF	R0	Whole bin (MacAdam 5 only)	R0
		SPMWH3327FS3GAR3SF	R3	MacAdam 3-step ellipse bin	RU
		SPMWH3327FS3GARYSF	RY	Y Kitting	RN, RP, RQ, RR, RS, RT, RU

d) Voltage Bins (I_F = 150 mA, T_s = 25℃)

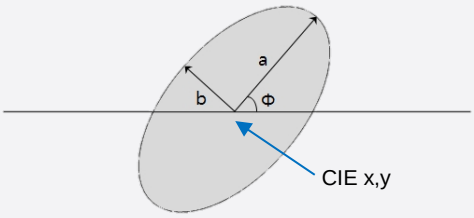
CRI (R_a) Min.	Nominal CCT (K)	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
-	-	-	GA	AZ	6.0 ~ 6.1
				A1	6.1 ~ 6.2
				A2	6.2 ~ 6.3
				A3	6.3 ~ 6.4

e) Chromaticity Region & Coordinates (I_F = 150 mA, T_s = 25℃)





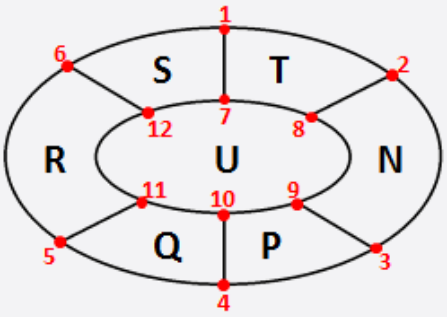
f) Chromaticity Region & Coordinates (I_F = 150 mA, T_s = 25℃)



MacAdam	CCT (K)	Center point		Major-axis	Minor-axis	Rotation
		CIE x	CIE y	a	b	Φ
3 step	3000	0.4338	0.4030	0.0083	0.0041	53.22
	3500	0.4073	0.3917	0.0093	0.0041	54.00
	4000	0.3818	0.3797	0.0094	0.0040	53.72
	5000	0.3447	0.3553	0.0082	0.0035	59.62
5 step	3000	0.4338	0.4030	0.0138	0.0068	53.22
	3500	0.4073	0.3917	0.0155	0.0068	54.00
	4000	0.3818	0.3797	0.0157	0.0067	53.72
	5000	0.3447	0.3553	0.0137	0.0058	59.62

Note: Samsung maintains measurement tolerance of: Cx, Cy = ±0.005

g) Chromaticity Region & Coordinates

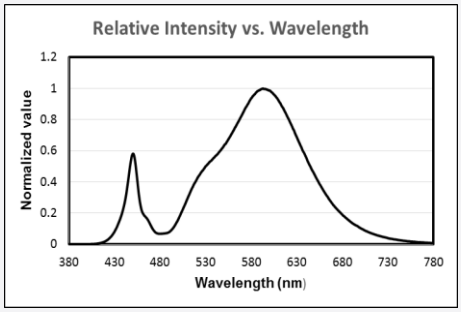


Region	3000K		3500K		4000K		5000K	
	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
1	0.4283	0.4071	0.4018	0.3957	0.3764	0.3837	0.3397	0.3583
2	0.4382	0.4146	0.4125	0.4046	0.3871	0.3926	0.3482	0.3670
3	0.4437	0.4105	0.4180	0.4005	0.3925	0.3887	0.3532	0.3640
4	0.4393	0.3989	0.4128	0.3877	0.3872	0.3758	0.3497	0.3524
5	0.4293	0.3913	0.4022	0.3788	0.3765	0.3668	0.3412	0.3436
6	0.4239	0.3954	0.3966	0.3828	0.3711	0.3707	0.3362	0.3465
7	0.4305	0.4054	0.4040	0.3941	0.3786	0.3821	0.3417	0.3571
8	0.4364	0.4100	0.4104	0.3994	0.3850	0.3874	0.3468	0.3623
9	0.4397	0.4075	0.4137	0.3970	0.3882	0.3851	0.3498	0.3605
10	0.4371	0.4005	0.4106	0.3893	0.3850	0.3773	0.3477	0.3535
11	0.4311	0.3960	0.4042	0.3840	0.3786	0.3720	0.3426	0.3483
12	0.4279	0.3984	0.4009	0.3864	0.3754	0.3743	0.3396	0.3500

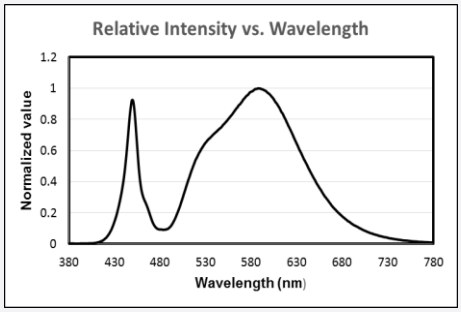
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 150 mA, T_S = 25 ºC)

CCT : 3000K (70 CRI)



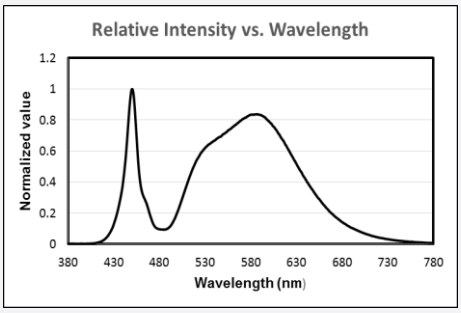
CCT : 3500K (70 CRI)



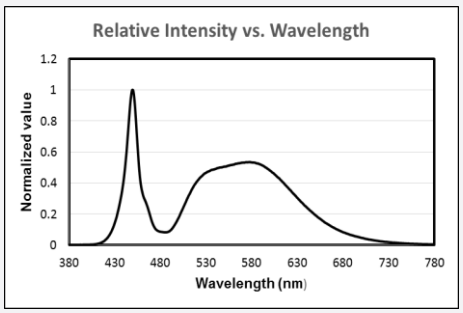
CCT : 4000K (70 CRI)

CCT : 5000K (70 CRI)

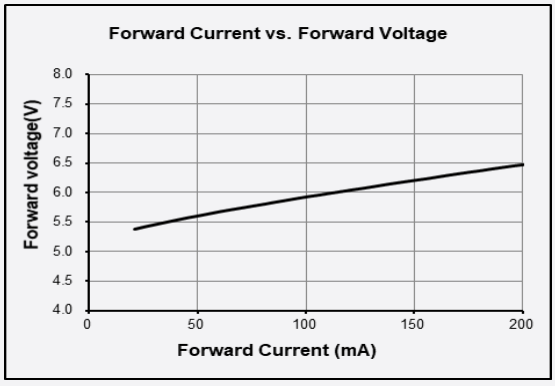
CCT : 4000K (70 CRI)

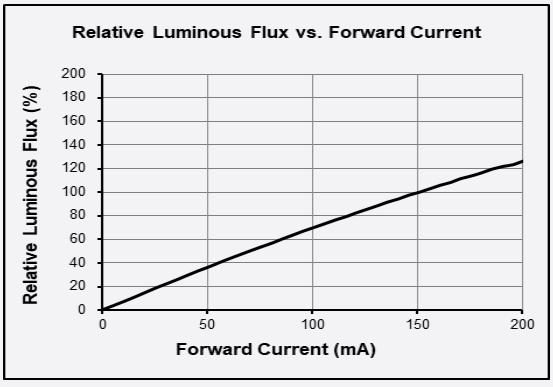


CCT : 5000K (70 CRI)

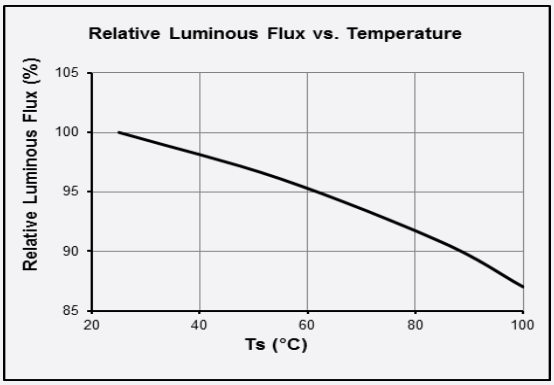


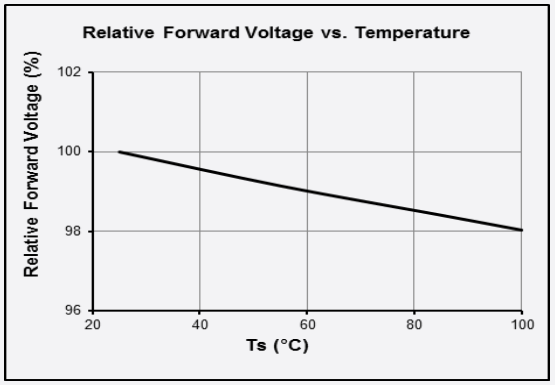
b) Forward Current Characteristics (I_F = 150 mA, T_S = 25 ºC)



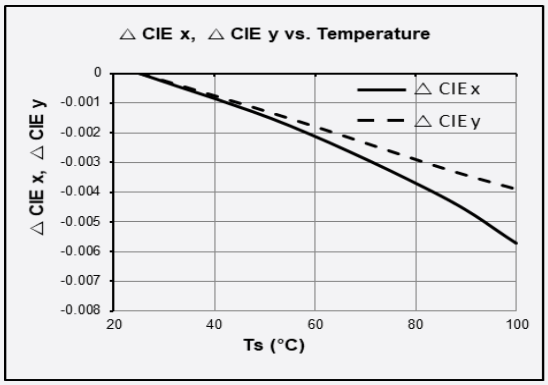


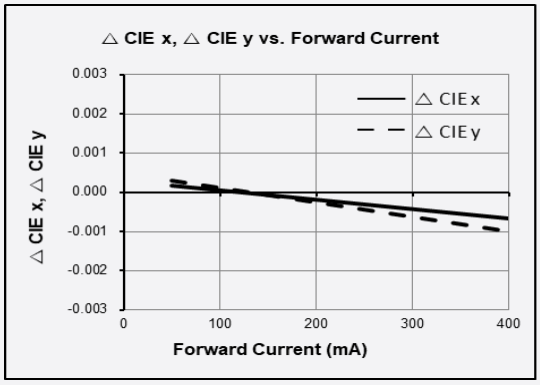
c) Temperature Characteristics (I_F = 150 mA)



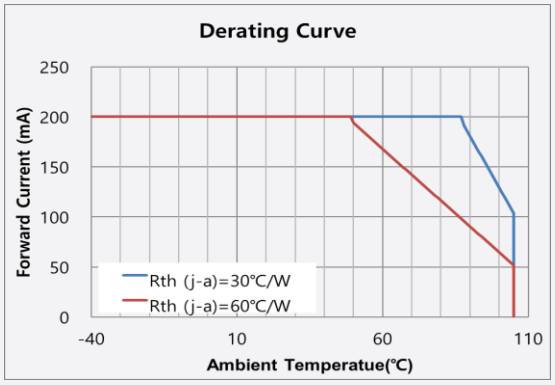


d) Color Shift Characteristics (Ts = 25 ºC, IF = 150mA)

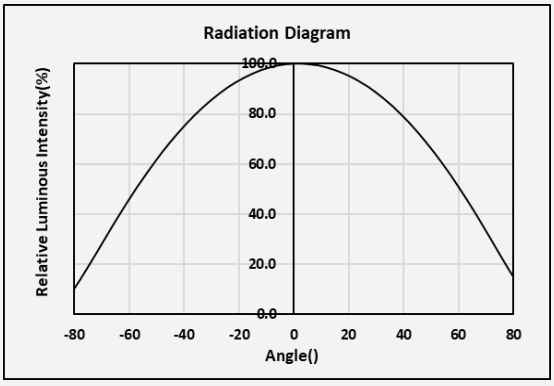




e) Derating Curve



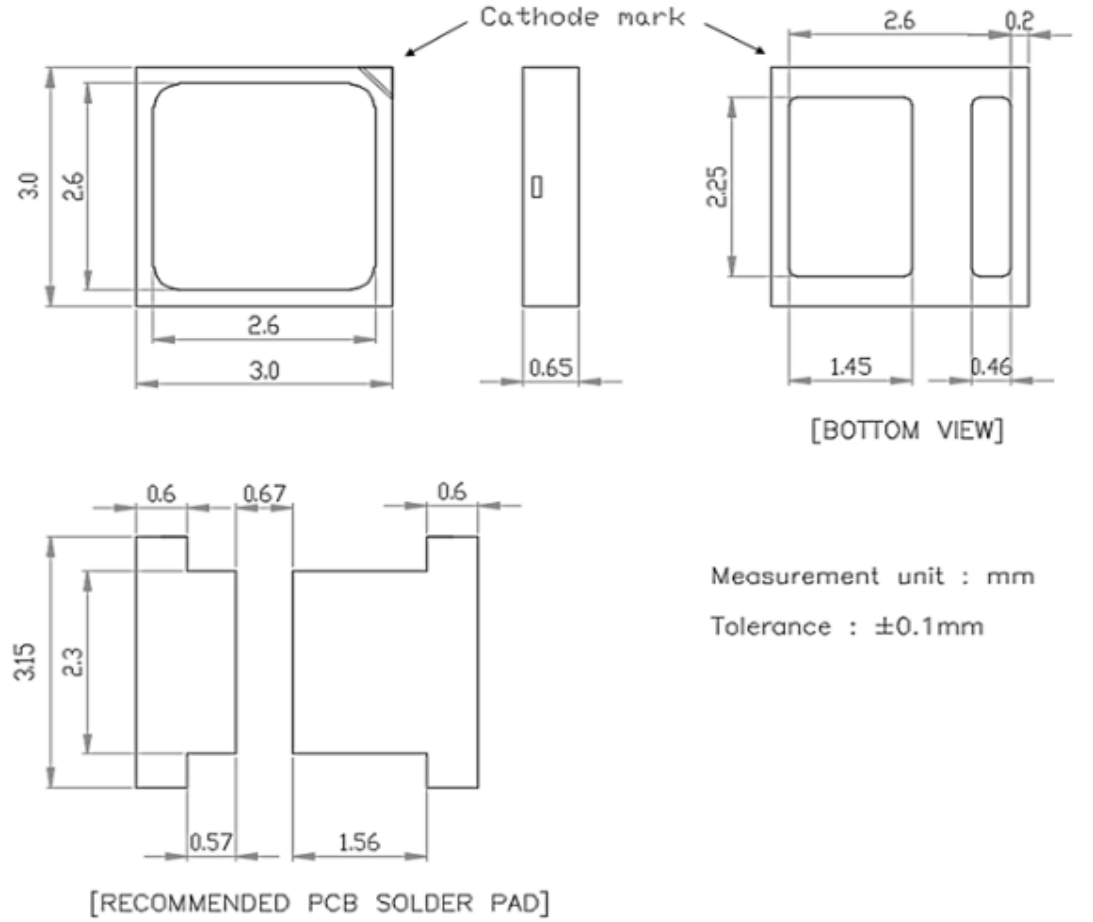
f) Beam Angle Characteristics (IF=150mA, Ts=25 ºC)



Note: All characteristics shown are for reference only.

Derating characteristics will meet the criteria as detailed in the Reliability section within this specification.

4. Outline Drawing & Dimension



Notes:

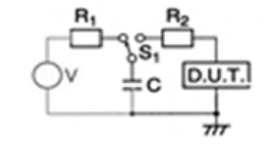
1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
2) T_s point and measurement method:
   ① Measure one point at the cathode pad, if necessary remove PSR of PCB to reach T_s point.
   ② All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

Precautions:

1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED`s characteristics should be carefully checked before and after such repair.
3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample No.
High Temperature Life Test	85 ºC, DC 200 mA	1000 h	22
High Temperature Humidity Life Test	60 ºC, 90 % RH, DC 200 mA	1000 h	22
Low Temperature Life Test	-40 ºC, DC 200 mA	1000 h	22
Thermal Cycle	-45 ºC / 15 min ↔ 125 ºC / 15 min → Hot plate 180 ºC	500 cycles	100
High Temperature Storage	120 ºC	1000 h	11
Low Temperature Storage	-40 ºC	1000 h	11
ESD (HBM)	 R_1: 10 MΩ R_2: 1.5 kΩ C: 100 pF V: ±5 kV	5 times	30

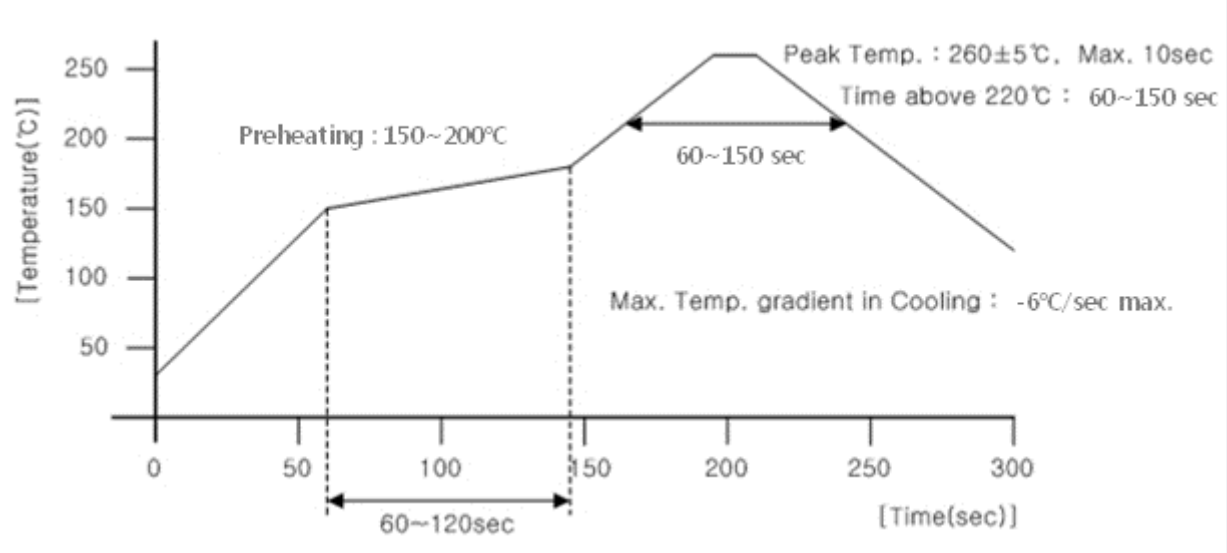
b) Criteria for Judging the Damage

Item	Symbol	Test Condition (T_s = 25 ºC)	Limit	
			Min	Max
Forward Voltage	V_F	I_F = 150 mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ_v	I_F = 150 mA	Init. Value * 0.7	Init. Value * 1.1

6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



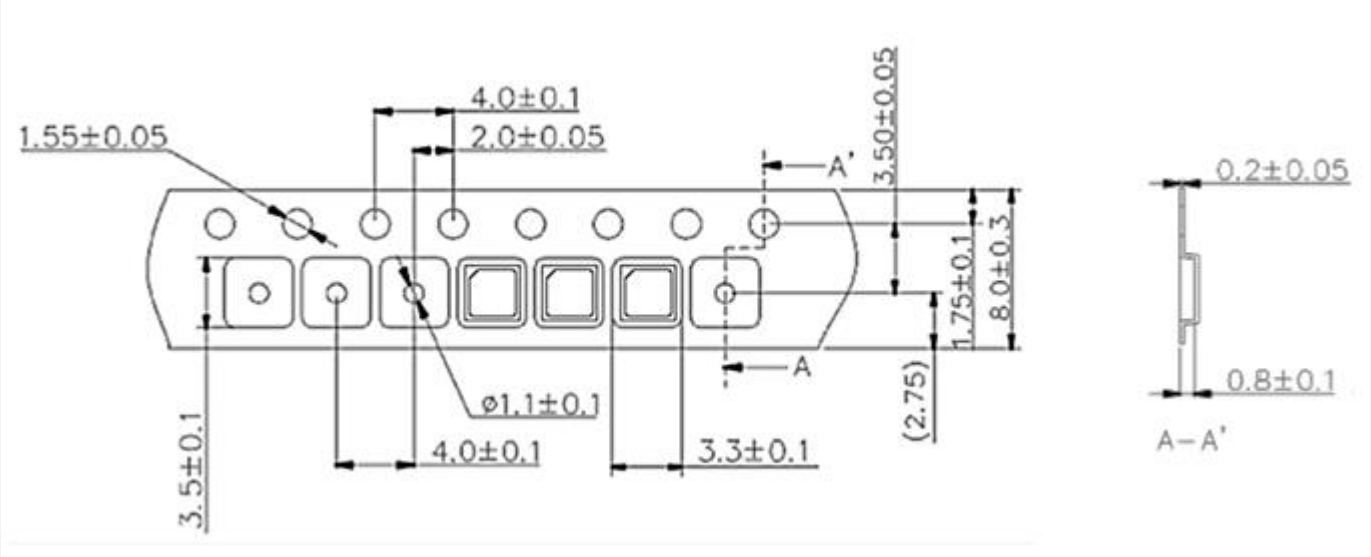
b) Manual Soldering Conditions

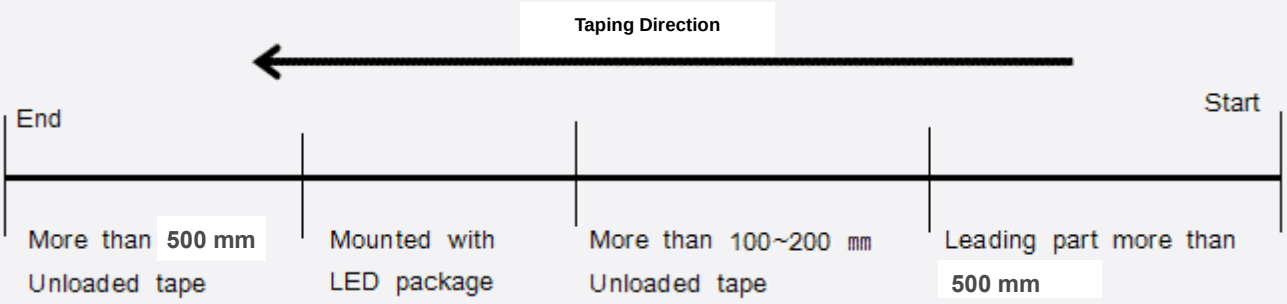
Not more than 5 seconds @ max. 300 ºC, under soldering iron.

7. Tape & Reel

a) Taping Dimension

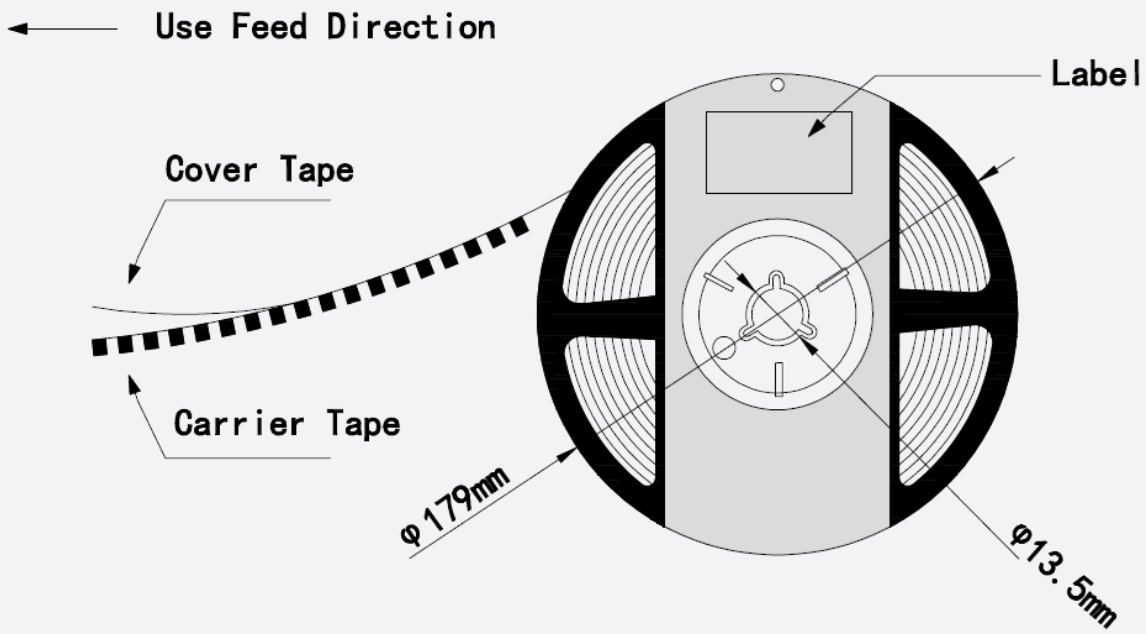
(unit: mm)





b) Reel Dimension

(unit: mm)

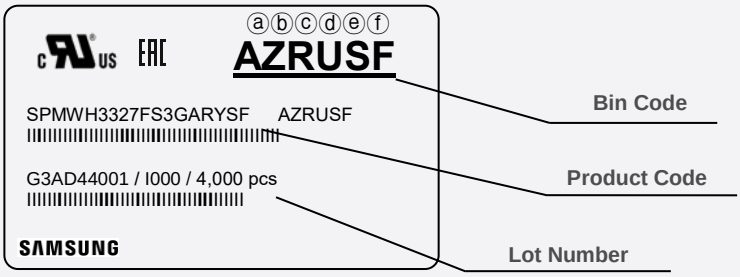


Notes:

1) Quantity: The quantity/reel is 4,000 pcs
2) Cumulative Tolerance: Cumulative tolerance / 10 pitches is ±0.2 mm
3) Adhesion Strength of Cover Tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

8. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

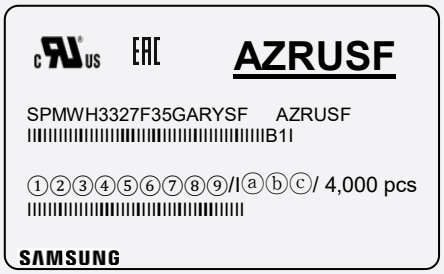
ⓐⓑ: Forward Voltage bin (refer to page 7)

ⓒⓓ: Chromaticity bin (refer to page 8-10)

ⓔⓕ: Luminous Flux bin (refer to page 5)

b) Lot Number

The lot number is composed of the following characters:



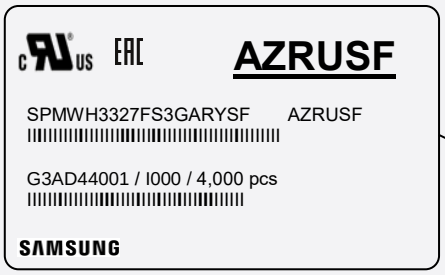
①②③④⑤⑥⑦⑧⑨ / Iⓐⓑⓒ / 4,000 pcs

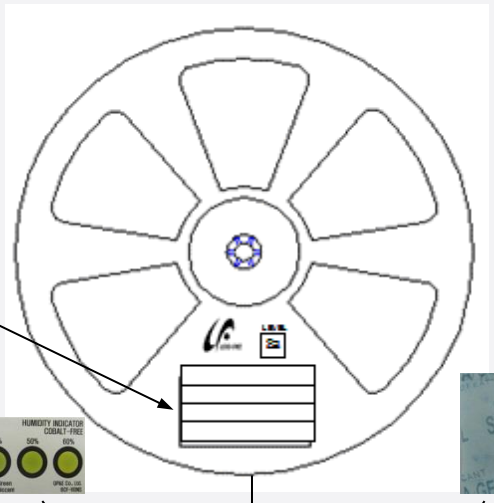
①②	:	Production site (G3 : Shenzhen, China)
③	:	Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
④	:	Year (C : 2018, D : 2019, E : 2020 …)
⑤	:	Month (1~9, A, B, C)
⑥	:	Day (1~9, A, B~V)
⑦⑧⑨	:	Serial number (001 ~ 999)
ⓐⓑⓒ	:	Product serial number (001 ~ 999)

9. Packing Structure

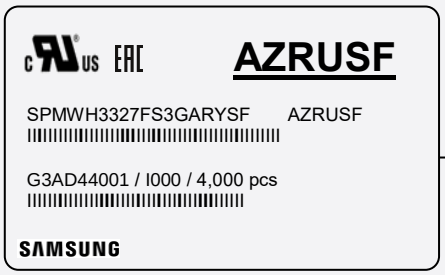
a) Packing Process (The quantity of PKG on the Reel to be Max 4,000pcs)

Reel





Aluminum Vinyl Packing Bag

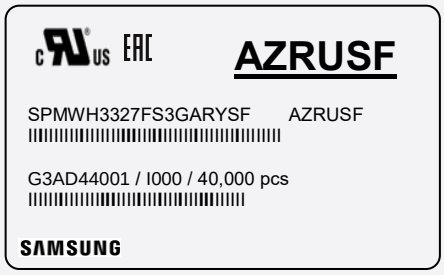


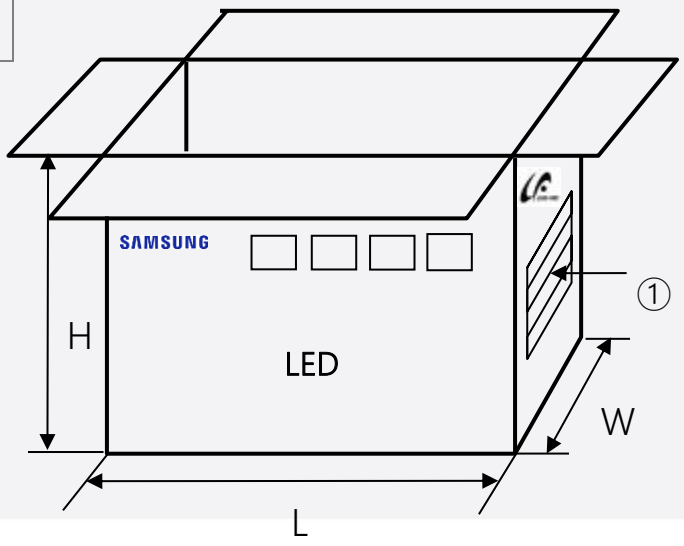
Outer Box

Material: Paper (SW3B(B))

Type	Size (mm)			Note
	L	W	H	
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels
7 inch S	245 ± 5	220 ± 5	86 ± 5	Up to 5 reels

① **Side Label**





b) Packing Process for kitting (The quantity of PKG on the Reel to be Max 4,000pcs)

Kitting 'A'

AZ★NSF

SPMWH3327FS3GA★YSF AZ★NSF

G3AD44001 / I000 / 4,000 pcs

SAMSUNG

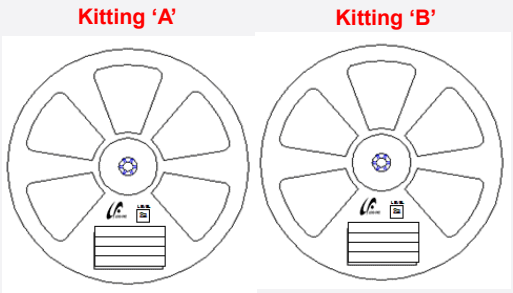
Kitting 'B'

AZ★RSF

SPMWH3327FS3GA★YSF AZ★RSF

G3AD44001 / I000 / 4,000 pcs

SAMSUNG



Aluminum Vinyl Packing Bag

Kitting 'A'

AZ★NSF

SPMWH3327FS3GA★YSF AZ★NSF

G3AD44001 / I000 / 4,000 pcs

SAMSUNG

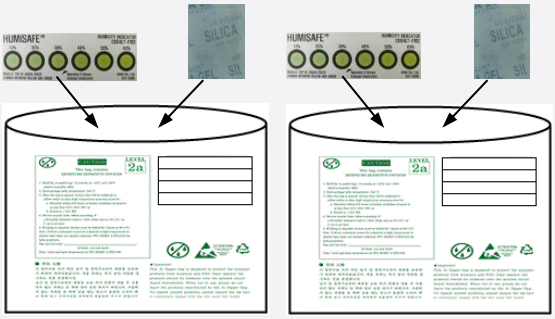
Kitting 'B'

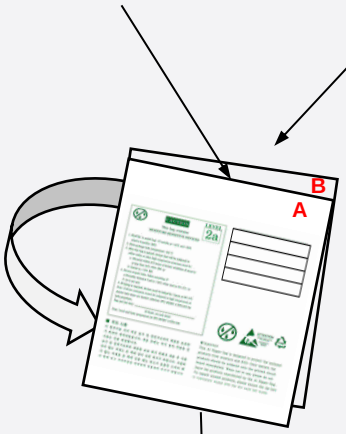
AZ★RSF

SPMWH3327FS3GA★YSF AZ★RSF

G3AD44001 / I000 / 4,000 pcs

SAMSUNG





Outer Box

Kitting 'A'

AZ★NSF

SPMWH3327FS3GA★YSF AZ★NSF

G3AD44001 / I000 / 20,000 pcs

SAMSUNG [BOX Label]

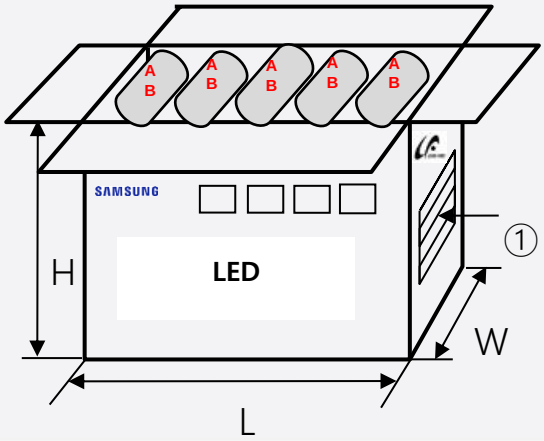
Kitting 'B'

AZ★RSF

SPMWH3327FS3GA★YSF AZ★RSF

G3AD44001 / I000 / 20,000 pcs

SAMSUNG [BOX Label]



Note: "★" can be Nominal CCT code.

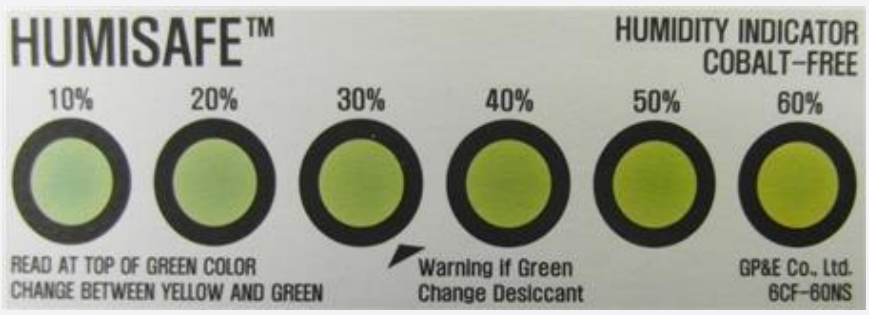
Material: Paper (SW3B(B))

Type	Size (mm)			Note
	L	W	H	
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels

c) Aluminum Vinyl Packing Bag

d) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag

(This image is for reference only. Silicagel and humidity indicator shapes may be different.)



10. Precautions in Handling & Use

1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.

2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.

3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.

4) LEDs must be stored in a clean environment. Shelf life of sealed bags is 12 months at temperature 0~40 ºC, 0~90 % RH.

5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:

a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 ºC / 60 % RH*Note 1, or
b. Mounted within 24 hours (1 day) at an assembly line with a condition of more than 30 ºC / 70 % RH*Note 2, or
c. Stored at <10 % RH.

*Note 1, 2: IPC/JEDEC J-STD-033A, Recommended Equivalent Total Floor Life Table

Package Type and Body Thickness	Moisture Sensitivity Level	Maximum Percent Relative Humidity						Temperature
		40%	50%	60%	70%	80%	90%	
Body Thickness <2.1mm	Level 2a	∞	∞	28	1	1	1	30℃
		∞	∞	∞	2	1	1	25℃
		∞	∞	∞	2	2	1	20℃

6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.

7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 ºC.

8) Devices must be baked for 10~24 hours at 60 ± 5 ºC, if baking is required.

9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.

10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.

11) Risk of sulfurization (or tarnishing)

The LED from Samsung uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as rubber, plain paper, lead solder cream, etc.

Legal and additional information.

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Samsung inspires the world and shapes the future with transformative ideas and technologies. The company is redefining the worlds of TVs, smartphones, wearable devices, tablets, digital appliances, network systems, and memory, system LSI, foundry and LED solutions. For the latest news, please visit the Samsung Newsroom at news.samsung.com.

Samsung Electronics Co., Ltd.
95, Samsung 2-ro
Giheung-gu
Yongin-si, Gyeonggi-do, 446-711
KOREA

www.samsungled.com

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